



DMT2004UFV

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
	5.0mΩ @ V <sub>GS</sub> = 10V	70A
24V	6.5mΩ @ V <sub>GS</sub> = 4.5V	60A
	10.0mΩ @ V <sub>GS</sub> = 2.5V	45A

### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- **Power Management Functions**
- **DC-DC Converters**

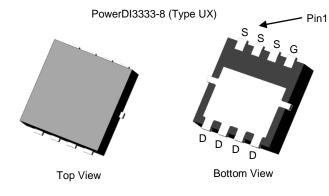
#### N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8 (Type UX)

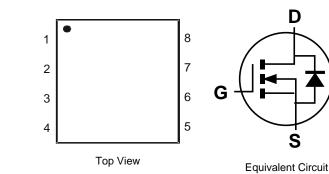
#### **Features and Benefits**

- Low R<sub>DS(ON)</sub> ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

# **Mechanical Data**

- Case: PowerDI<sup>®</sup>3333-8 (Type UX) •
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.072 grams (Approximate)





#### Ordering Information (Note 4)

	Part Number	Case	Packaging			
	DMT2004UFV-7	PowerDI3333-8 (Type UX)	2,000/Tape & Reel			
DMT2004UFV-13 PowerDI3333-8 (Type UX) 3,000/Tape & Reel						
Notes:	Notes: 1. No purposely added lead, Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

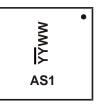
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



<u>AS1</u> = Product Type Marking Code YYWW = Date Code Marking  $\overline{YY}$  = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	24	V		
Gate-Source Voltage	V <sub>GSS</sub>	±12	V		
Continuous Drain Current (Note 7) $V_{GS} = 10V$	ID	70 55	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	90	A		
Continuous Source-Drain Diode Current (Note 6)	ls	2.5	A		
Avalanche Current (Note 8) L = 0.1mH	I <sub>AS</sub>	26	A		
Avalanche Energy (Note 8) L = 0.1mH			E <sub>AS</sub>	36	mJ

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	1.2	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	106	°C/W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	54	°C/W
Thermal Resistance, Junction to Case (Note 7)	R <sub>θ</sub> JC	3.5	°C/W	
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (T<sub>A</sub> = +25°C, unless otherwise specified.)

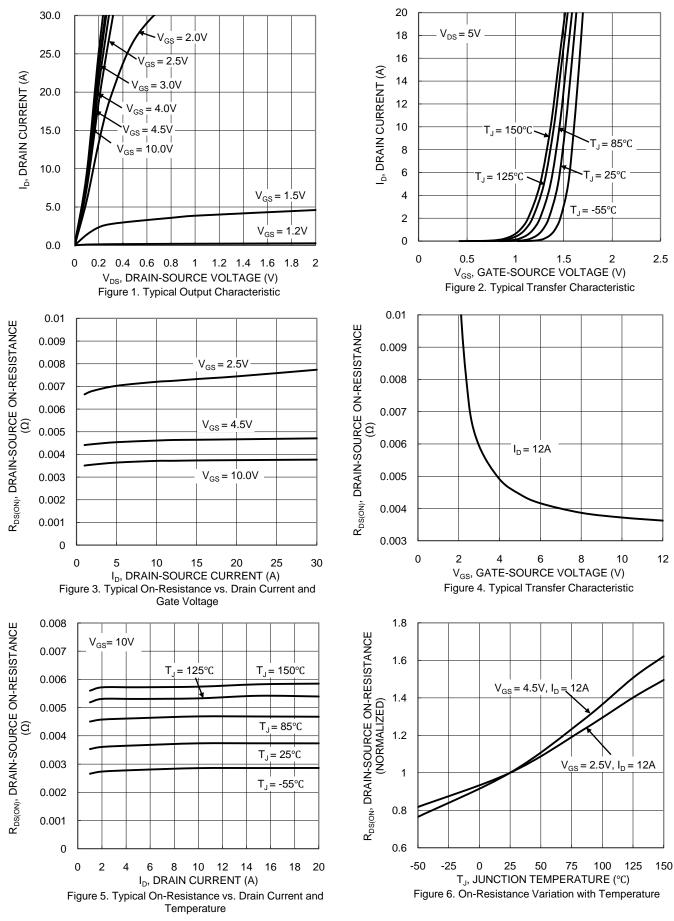
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	24	_	—	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current (T <sub>J</sub> = +25°C)	IDSS	_	_	1	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	—		±100	nA	$V_{GS} = \pm 10V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.55	—	1.45	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
			3.8	5.0	mΩ	$V_{GS} = 10V, I_D = 12A$	
Static Drain-Source On-Resistance	RDS(ON)	—	4.6	6.5		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 12A	
		—	6.8	10.0		V <sub>GS</sub> = 2.5V, I <sub>D</sub> = 12A	
Diode Forward Voltage	V <sub>SD</sub>	_	0.65	1.0	V	$V_{GS} = 0V, I_{S} = 2A$	
DYNAMIC CHARACTERISTICS (Note 10)						÷	
Input Capacitance	Ciss	-	1683	—		$V_{DS}$ = 15V, $V_{GS}$ = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	581	—	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	559	—			
Gate Resistance	R <sub>G</sub>	_	1.6	—	Ω	V <sub>DS</sub> = 0V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	29.6	_			
Total Gate Charge (V <sub>GS</sub> = 10V)	Qq	_	53.7	—	nC	$V_{DD} = 15V, I_D = 9A$	
Gate-Source Charge	Q <sub>gs</sub>	_	4.2	—	nc		
Gate-Drain Charge	Q <sub>gd</sub>	_	13.4	—			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	3.9	—		$V_{DD}$ = 15V, $V_{GS}$ = 10V, $R_G$ = 3 $\Omega$ , $I_D$ = 9A	
Turn-On Rise Time	t <sub>R</sub>	_	9.6	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	30.8	_	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	38.6	_	1		
Reverse Recovery Time	t <sub>RR</sub>	_	11.2	_	ns		
Reverse Recovery Charge	harge Q <sub>RR</sub> — 22.9 — nC		nC	I <sub>F</sub> = 1.5A, di/dt = 100A/µs			

Notes:

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Thermal resistance from junction to soldering point (on the exposed drain pad).
8. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.
9. Short duration pulse test used to minimize self-heating effect.
10. Guaranteed by design. Not subject to product testing.



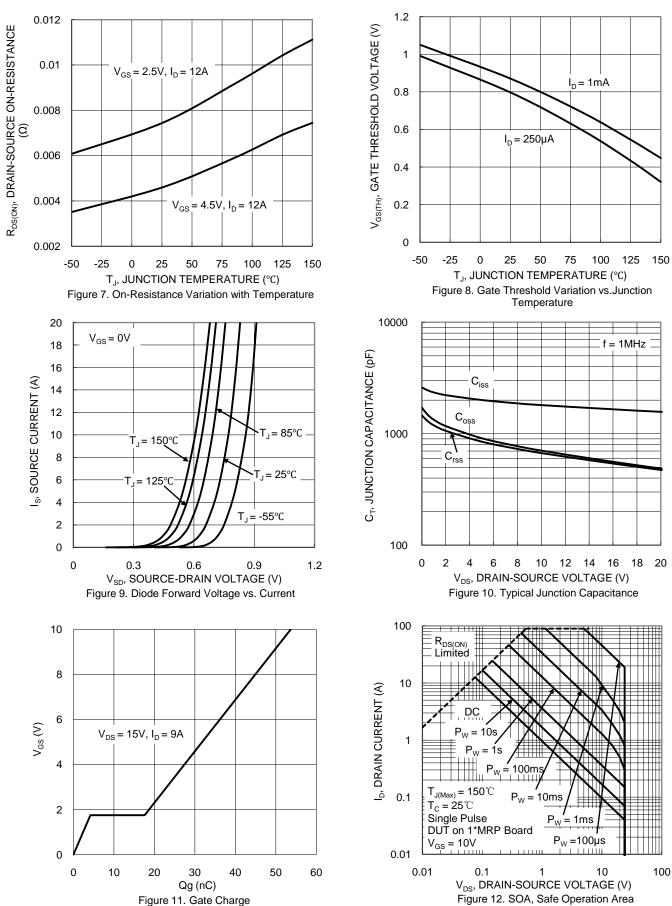
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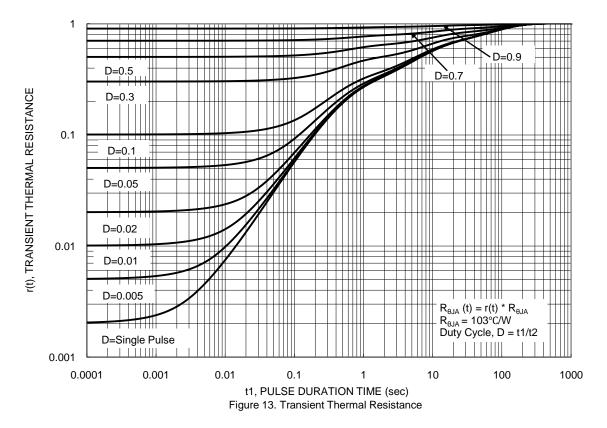
DMT2004UFV Document number: DS40671 Rev. 2 - 2



### DMT2004UFV





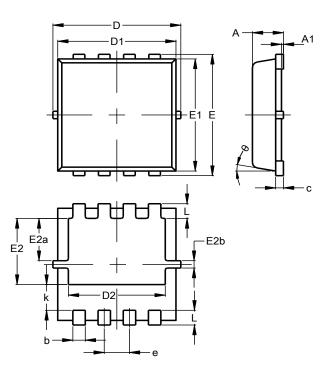




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (Type UX)

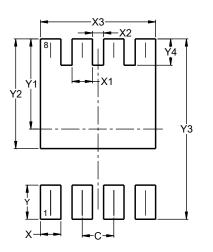


PowerDI3333-8						
(Type UX)						
Dim	Min Max		Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
c	0.10	0.25	0.15			
D	3.20	3.20 3.40 3.3				
D1	2.95	2.95 3.15				
D2	2.30	2.70	2.50			
E	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	1.60 2.00 1.8				
E2a	0.95	1.35	1.15			
E2b	0.10	0.30	0.20			
e	0.65 BSC					
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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